• #2/6/26/0/ Patent Dade

Group Art Unit: Not Yet Assigned

Date: March 19, 2001

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of: David J. Norris

Serial No.: Not Yet Assigned

Filed: Herewith Examiner: Not Yet Assigned

• For: METHOD FOR MANUFACTURING HIGH-QUALITY

MANGANESE-DOPED SEMICONDUCTOR

NANOCRYSTALS

1c821 U.S. PTO 09/811674

FILING OF INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. 1.97-1.98

ASSISTANT COMMISSIONER FOR PATENTS WASHINGTON, D.C. 20231

Dear Sir:

Pursuant to the duty of disclosure of information material to the patentability of claims in the above-captioned patent application under 37 C.F.R. 1.56, submitted herewith is a completed Form PTO-1449 and a copy of each reference cited therein.

Authorization is hereby given to charge any fees which may be required, except the issue fee, to Deposit Account 14-0627.

Respectfully submitted,

Andrew G. Isztwan, Esq.

Reg. No. 40,028 (609) 951-2533



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FORM PTO-1449 (Modified)	ATTY. DOCKET NO. NECI1085 SERIAL NO. Not Yet Ass	igned 2
LIST OF PATENTS AND PUBLICATION FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	ONS APPLICANT David J. Norris	
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